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Carbon Nanotubes, Graphene, and Associated Devices V

**Didier Pribat
Young-Hee Lee
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Editors

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Contents

vii Conference Committee

SESSION 1 GROWTH AND DEVICE TECHNOLOGY I

- 8462 03 **Chemical vapor deposition of graphene on copper at reduced temperatures** [8462-2]
E. M. Gallo, B. I. Willner, Structured Materials Industries, Inc. (United States); J. Hwang, Cornell Univ. (United States); S. Sun, Structured Materials Industries, Inc. (United States); M. Spencer, Cornell Univ. (United States); T. Salagaj, Structured Materials Industries, Inc. (United States); W. C. Mitchel, Air Force Research Lab. (United States); N. Sbrockey, G. S. Tompa, Structured Materials Industries, Inc. (United States)
- 8462 04 **A novel multi-wall CNT synthesis technique using conventional CVD with controlled pressure** [8462-3]
M. H. S. Kara, M. H. Amir, A. A. Teh, R. Ahmad, M. R. Mahmood, Z. Awang, Univ. Teknologi MARA (Malaysia)
- 8462 05 **Investigation of the behavior of the Ni catalyst in chemical vapor deposition synthesis of carbon nanopearls** [8462-4]
S. Pacley, W. Mitchell, Air Force Research Lab. (United States); P. T. Murray, D. Anderson, H. E. Smith, Univ. of Dayton Research Institute (United States); E. Beck-Millerton, A. A. Voevodin, Air Force Research Lab. (United States)

SESSION 2 GROWTH AND DEVICE TECHNOLOGY II

- 8462 06 **Fabrication and *ab initio* study of downscaled graphene nanoelectronic devices (Invited Paper)** [8462-5]
H. Mizuta, Univ. of Southampton (United Kingdom) and Japan Advanced Institute of Science and Technology (Japan); Z. Moktadir, S. A. Boden, N. Kalhor, S. Hang, M. E. Schmidt, Univ. of Southampton (United Kingdom); N. T. Cuong, D. H. Chi, N. Otsuka, M. Muruganathan, Japan Advanced Institute of Science and Technology (Japan); Y. Tsuchiya, H. Chong, H. N. Rutt, D. M. Bagnall, Univ. of Southampton (United Kingdom)
- 8462 07 **Advancing quasi-freestanding epitaxial graphene electronics through integration of wafer scale hexagonal boron nitride dielectrics** [8462-6]
M. S. Bresnehan, M. J. Hollander, R. L. Marucci, M. LaBella, K. A. Trumbull, R. Cavalero, D. W. Snyder, J. A. Robinson, The Pennsylvania State Univ. (United States)

SESSION 3 MICROWAVE AND TERAHERTZ APPLICATIONS I

- 8462 0A **Modeling and experimental verification of graphene co-planar waveguide transmission lines** [8462-9]
Z. Awang, M. H. Kara, M. H. Amir, A. Awang Teh, M. R. Mahmood, Univ. Teknologi MARA (Malaysia)

- 8462 OB **Performance assessment of optimized carbon-nanotube-based wireless on-chip communication** [8462-10]
P. Franck, CINTRA CNRS/NTU/Thales (Singapore) and XLIM, Univ. de Limoges, CNRS (France); D. Baillargeat, CINTRA CNRS/NTU/Thales (Singapore); B. Tay, CINTRA CNRS/NTU/Thales (Singapore) and Nanyang Technological Univ. (Singapore)

SESSION 4 MICROWAVE AND TERAHERTZ APPLICATIONS II

- 8462 OC **Terahertz conductivity studies in carbon nanotube networks prepared by the vacuum filtration method (Invited Paper)** [8462-11]
H. Lamela, E. Dadrasnia, Univ. Carlos III de Madrid (Spain); D.-M. Lee, S. Baik, Sungkyunkwan Univ. (Korea, Republic of); M. B. Kuppam, F. Garet, J.-L. Coutaz, IMEP-LAHC, Univ. de Savoie (France)
- 8462 OE **Studying and analyzing terahertz signals in carbon nanostructures thin-films** [8462-13]
E. Dadrasnia, H. Lamela, Univ. Carlos III de Madrid (Spain)

SESSION 5 OPTICAL INTERACTIONS I

- 8462 OH **Infrared transmission spectroscopy of CVD graphene on Si** [8462-16]
S. Mou, S. S. Kim, Air Force Research Lab. (United States); K.-H. Chen, Academia Sinica (Taiwan); L.-C. Chen, National Taiwan Univ. (Taiwan); R. R. Naik, G. J. Brown, W. C. Mitchel, Air Force Research Lab. (United States)

SESSION 6 OPTICAL INTERACTIONS II

- 8462 OJ **Characterization of carbon nano-materials by apertureless near-field scanning optical microscope-Raman spectroscopy (Invited Paper)** [8462-18]
K.-D. Park, Gwangju Institute of Science and Technology (Korea, Republic of); Y. H. Kim, Sungkyunkwan Univ. (Korea, Republic of); J. H. Park, J. S. Park, Gwangju Institute of Science and Technology (Korea, Republic of); Y.-H. Lee, Sungkyunkwan Univ. (Korea, Republic of); M. S. Jeong, Gwangju Institute of Science and Technology (Korea, Republic of)
- 8462 OK **Applications of single-walled carbon nanotubes and type-II quantum dots in photovoltaics and passive mode-locking saturable absorbers** [8462-19]
J. Tang, Y.-G. Wang, S.-M. Cheng, P. Yu, K.-Y. Huang, C.-T. Yuan, Academia Sinica (Taiwan)
- 8462 OL **Charge transfer effects in graphene-CdSe/ZnS quantum dots composites** [8462-20]
A. V. Klekachev, I. Asselberghs, IMEC (Belgium) and Katholieke Univ. Leuven (Belgium); S. N. Kuznetsov, Petrozavodsk State Univ. (Russian Federation); M. Cantoro, IMEC (Belgium) and Katholieke Univ. Leuven (Belgium); J. H. Mun, B. J. Cho, KAIST (Korea, Republic of); J. Hotta, J. Hofkens, Katholieke Univ. Leuven (Belgium); M. van der Veen, IMEC (Belgium); A. L. Stesmans, Katholieke Univ. Leuven (Belgium); M. M. Heyns, S. De Gendt, IMEC (Belgium) and Katholieke Univ. Leuven (Belgium)

SESSION 7 MISCELLANEOUS APPLICATIONS

- 8462 OR **Ballasted and electrically steerable carbon nanotube field emitters (Invited Paper)**
[8462-27]
M. T. Cole, Univ. of Cambridge (United Kingdom) and AIXTRON Ltd. (United Kingdom); C. Li, Univ. of Cambridge (United Kingdom) and Southeast Univ. (China); K. Qu, Southeast Univ. (China); Y. Zhang, Univ. of Cambridge (United Kingdom); B. Wang, Southeast Univ. (China); D. Pribat, Sungkyunkwan Univ. (Korea, Republic of); W. I. Milne, Univ. of Cambridge (United Kingdom) and Kyung Hee Univ. (Korea, Republic of)
- 8462 OT **Modified carbon nanotubes: from nanomedicine to nanotoxicology (Invited Paper)**
[8462-29]
M. Bottini, Burnham Institute for Medical Research (United States) and Univ degli Studi di Roma Tor Vergata (Italy); N. Bottini, La Jolla Institute for Allergy and Immunology (United States)

POSTER SESSION

- 8462 OU **Development of carbon nanotube paste for dye-sensitized solar cells** [8462-30]
M. Tsuji, S. Sugiyama, T. Oya, Yokohama National Univ. (Japan)
- 8462 OX **Transparent conducting carbon nanotubes thin films on the flexible substrate** [8462-33]
H.-C. Chen, H.-Y. Chiu, K.-T. Huang, Y.-S. Lo, C.-H. He, National Yunlin Univ. of Science and Technology (Taiwan)

Author Index

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- 1 Growth and Device Technology I
Seunghyun Baik, Sungkyunkwan University (Korea, Republic of)
- 2 Growth and Device Technology II
Didier Pribat, Sungkyunkwan University (Korea, Republic of)
- 3 Microwave and Terahertz Applications I
Horacio Lamela Rivera, Universidad Carlos III de Madrid (Spain)

- 4 Microwave and Terahertz Applications II
Woojae Kim, Kyungwon University (Korea, Republic of)
- 5 Optical Interactions I
Didier Pribat, Sungkyunkwan University (Korea, Republic of)
- 6 Optical Interactions II
Seong Chan Jun, Yonsei University (Korea, Republic of)
- 7 Thin Film Transistors, Sensors, and Related Applications
Matthew T. Cole, University of Cambridge (United Kingdom)
- 8 Miscellaneous Applications
Gilles A Feugnet, Thales Research & Technology (France)